

# MAC8DG, MAC8MG, MAC8NG

Surface Mount – 400V -800V



## Description

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required. The MAC8xG series is designed for high performance full-wave AC control applications where high noise immunity and high commutating di/dt are required.

## Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 8.0 Amperes RMS at 100°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dv/dt – 250 V/μs minimum at 125°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220 Package
- High Commutating di/dt – 6.5 A/ms minimum at 125°C
- These Devices are Pb-Free and are RoHS Compliant

## Additional Information



Resources

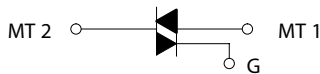


Accessories

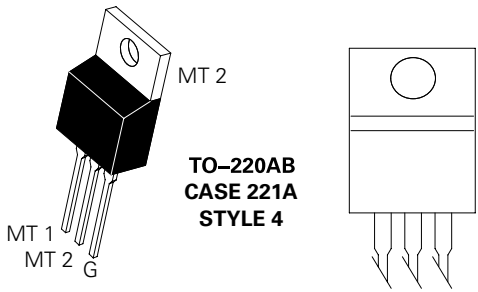


Samples

## Functional Diagram



## Pin Out



# MAC8DG, MAC8MG, MAC8NG

## Surface Mount – 400V -800V

### Maximum Ratings ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = -40^\circ$ to $125^\circ\text{C}$ )	$V_{\text{DRM}}$ $V_{\text{RRM}}$	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_C = 100^\circ\text{C}$ )	$I_{\text{T(RMS)}}$	8.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_C = 125^\circ\text{C}$ )	$I_{\text{TSM}}$	80	A
Circuit Fusing Consideration ( $t = 8.3$ ms)	$I^2t$	26	A <sup>2</sup> sec
Peak Gate Power (Pulse Width $\leq 1.0$ $\mu\text{s}$ , $T_C = 80^\circ\text{C}$ )	$P_{\text{GM}}$	16	W
Average Gate Power ( $t = 8.3$ ms, $T_J = 80^\circ\text{C}$ )	$P_{\text{G(AV)}}$	0.35	W
Operating Junction Temperature Range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{\text{stg}}$	-40 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1.  $V_{\text{DRM}}$  and  $V_{\text{RRM}}$  for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

### Thermal Characteristics

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (AC) Junction-to-Ambient	$R_{\theta\text{JC}}$ $R_{\theta\text{JA}}$	2.2 62.5	$^\circ\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	$T_L$	260	$^\circ\text{C}$

### Electrical Characteristics - OFF ( $T_J = 25^\circ\text{C}$ unless otherwise noted ; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
Peak Repetitive Blocking Current ( $V_D = V_{\text{DRM}} = V_{\text{RRM}}$ ; Gate Open)	$I_{\text{DRM}}$ $I_{\text{RRM}}$	-	-	0.01 2.0	mA

### Electrical Characteristics - ON ( $T_J = 25^\circ\text{C}$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
Peak On-State Voltage (Note 4) ( $I_{\text{TM}} = \pm 6.0$ A)	$V_{\text{TM}}$	-	1.3	1.6	V
Gate Trigger Current (Continuous dc) ( $V_D = 12$ V, $R_L = 100$ $\Omega$ )	$I_{\text{GT}}$	5.0	13 16 18	35.0 35.0 35.0	mA
Holding Current ( $V_D = 12$ V, Gate Open, Initiating Current = $\pm 150$ mA)	$I_{\text{H}}$	-	20	40	mA
Latching Current ( $V_D = 24$ V, $I_G = 35$ mA)	$I_{\text{L}}$	-	20 30 20	50 80 50	mA
Gate Trigger Voltage ( $V_D = 12$ V, $R_L = 100$ $\Omega$ )	$V_{\text{GT}}$	0.5	0.69 0.77 0.72	1.5 1.5 1.5	V
Gate Non-Trigger Voltage ( $T_J = 125^\circ\text{C}$ ) ( $V_D = 12$ V, $R_L = 100$ $\Omega$ )	$V_{\text{GD}}$	0.2	- - -	- - -	V

2. Indicates Pulse Test: Pulse Width  $\leq 2.0$  ms, Duty Cycle  $\leq 2\%$ .

# MAC8DG, MAC8MG, MAC8NG

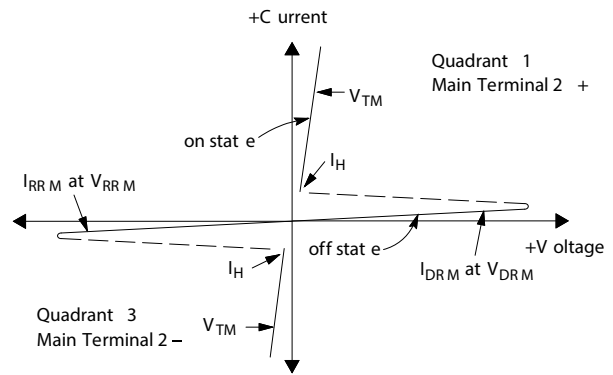
Surface Mount – 400V -800V

## Dynamic Characteristics

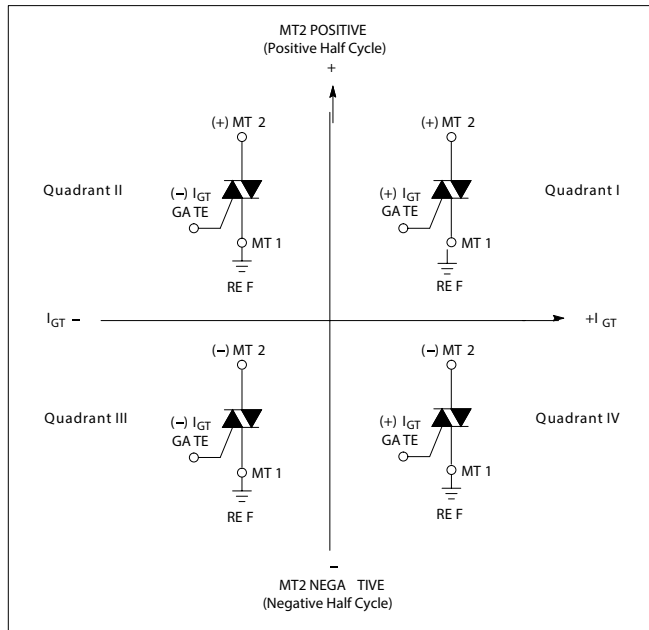
Characteristic	Symbol	Min	Typ	Max	Unit
Rate of Change of Commutating Current See Figure 10. ( $V_D = 400V$ , $I_{TM} = 4.4A$ , Commutating $dv/dt = 18V/\mu s$ , Gate Open, $T_J = 125^\circ C$ , $f = 250Hz$ , No Snubber) $C_L = 10\mu F$ $L_L = 40mH$	$(dv/dt)_c$	6.5	–	–	A/ms
Critical Rate of Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}$ , Exponential Waveform, Gate Open, $T_J = 125^\circ C$ )	$dV/dt$	250	–	–	V/ $\mu s$

## Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current



## Quadrant Definitions for a Triac

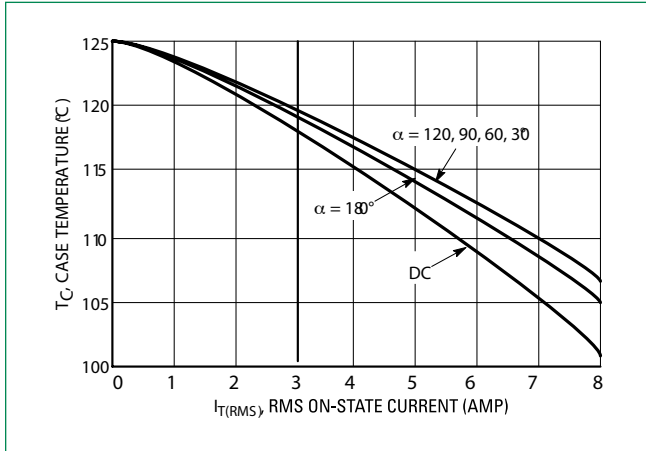


All polarities are referenced to MT1.  
With in-phase signals (using standard AC lines) quadrants I and III are used

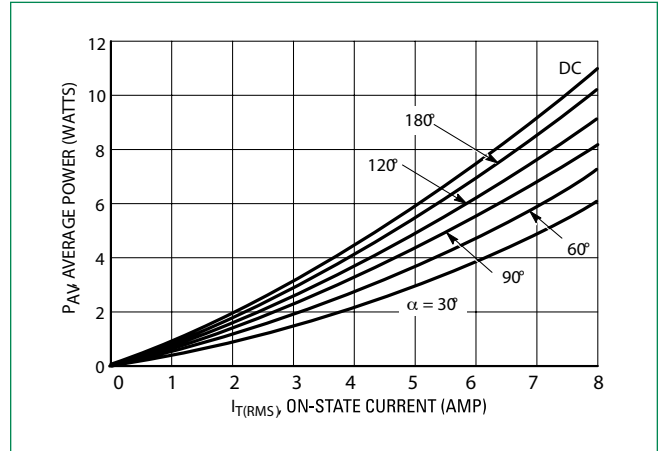
# MAC8DG, MAC8MG, MAC8NG

Surface Mount – 400V -800V

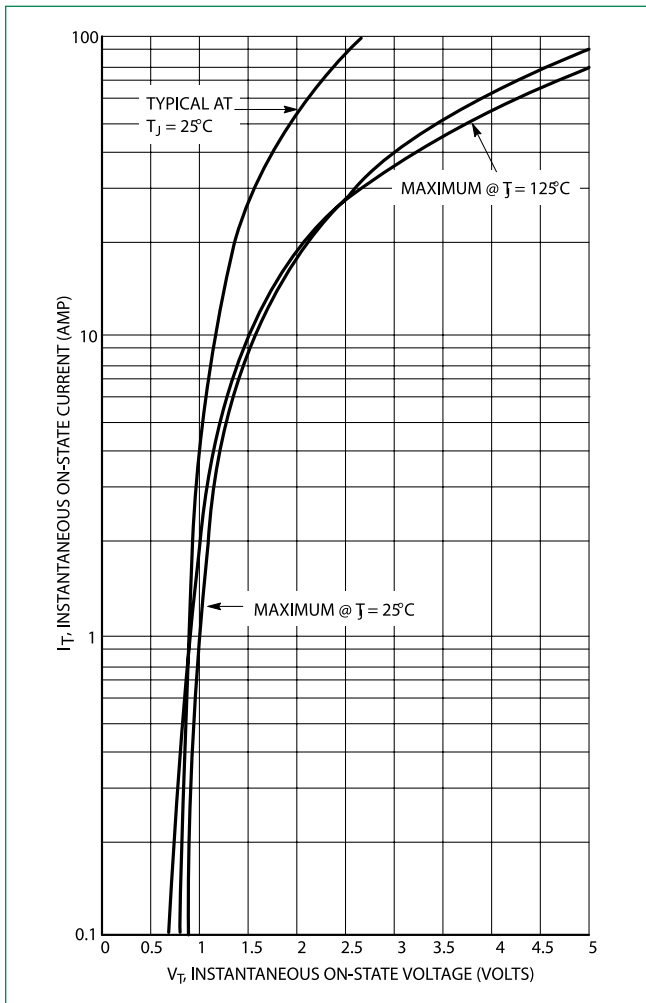
**Figure 1. RMS Current Derating**



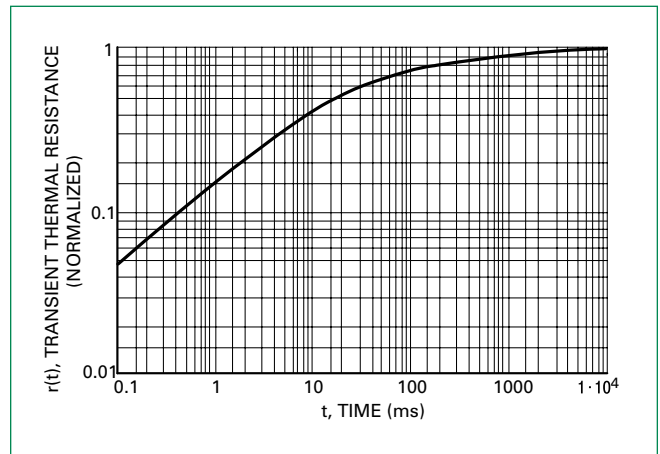
**Figure 2. On-State Power Dissipation**



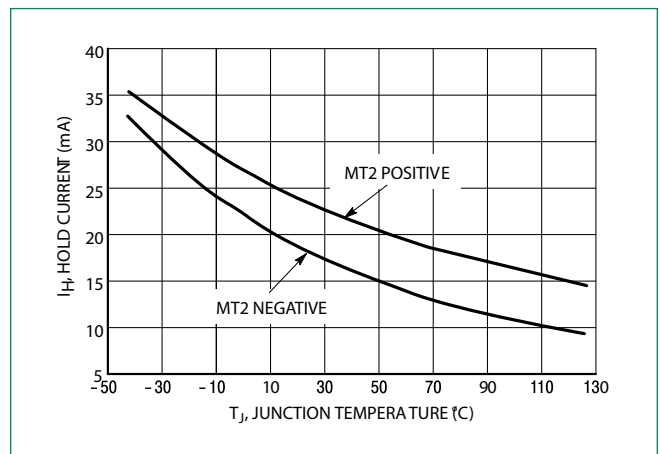
**Figure 3. On-State Characteristics**



**Figure 4. Thermal Response**



**Figure 5. Hold Current Variation**



# MAC8DG, MAC8MG, MAC8NG

Surface Mount – 400V -800V

Figure 6. Gate Trigger Current Variation

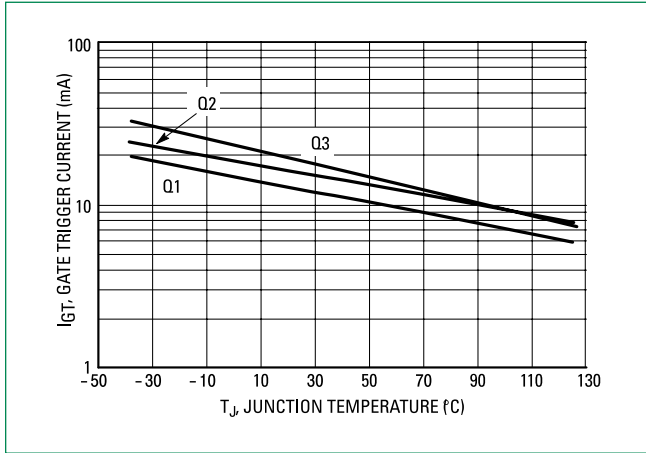


Figure 7. Gate Trigger Voltage Variation

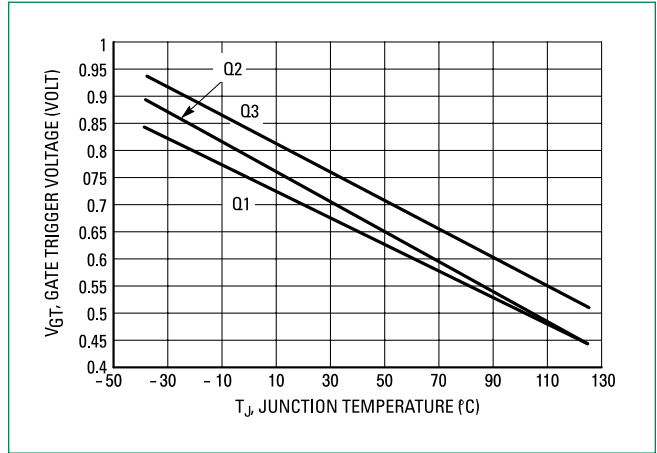


Figure 8. Critical Rate of Rise of Off-State Voltage (Exponential)

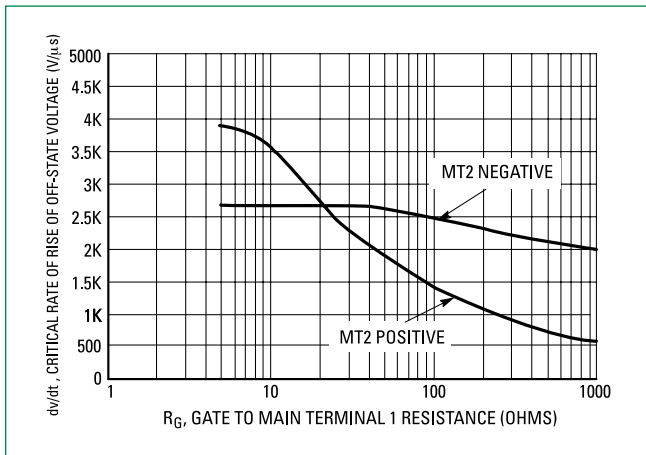


Figure 9. Critical Rate of Rise of Commutating Voltage

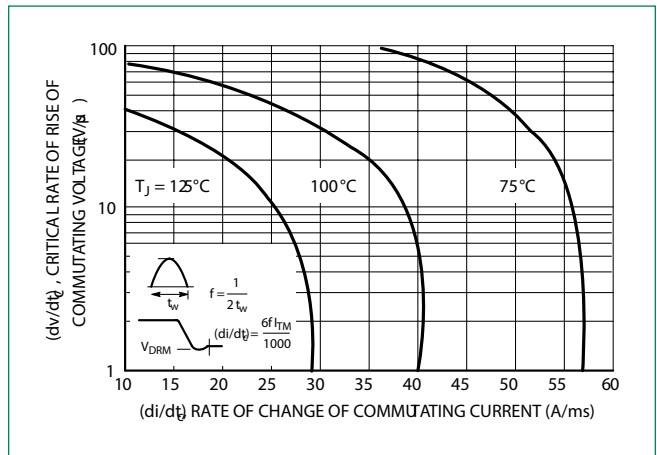
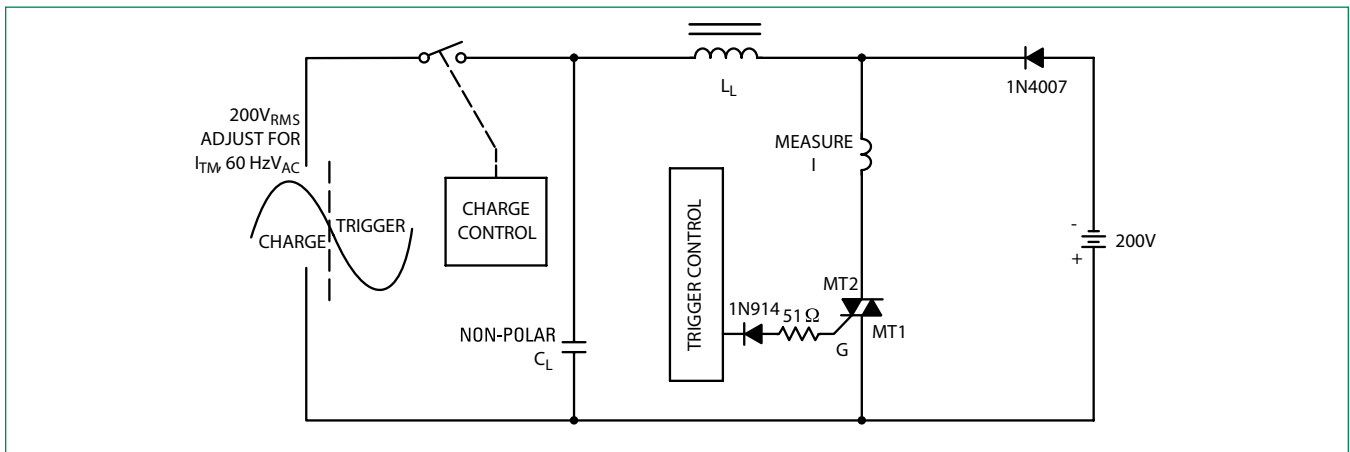


Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

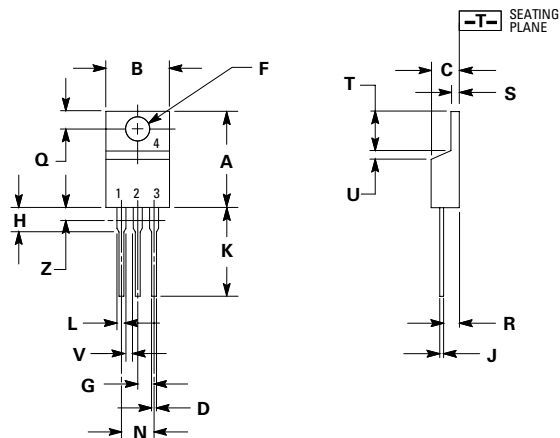


Note: Component values are for verification of rated  $(di/dt)$ . See AN1048 for additional information

# MAC8DG, MAC8MG, MAC8NG

## Surface Mount – 400V -800V

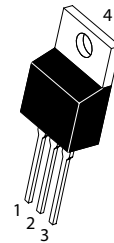
### Dimensions



Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.590	0.620	14.99	15.75
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
H	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
K	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
N	0.195	0.205	4.95	5.21
Q	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

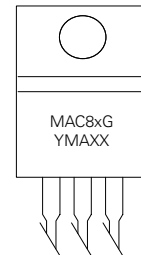
1. Dimensioning and tolerancing per ansi y14.5m, 1982.
2. Controlling dimension: inch.
3. Dimension z defines a zone where all body and lead irregularities are allowed.

### Part Marking System



**TO-220AB  
CASE 221A  
STYLE 12**

x =D, M, or N  
Y =Year  
M =Month  
A =Assembly Site  
XX =Lot Serial Code  
G =Pb-Free Package



Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

### Ordering Information

Device	Package	Shipping
MAC8DG	TO-220AB (Pb-Free)	1000 Units / Box
MAC8MG		
MAC8NG		

**Disclaimer Notice** - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <http://www.littelfuse.com/disclaimer-electronics>.